SINGLE-CHIP, MULTIPLE-MESSAGES
VOICE RECORD/PLAYBACK DEVICES
8-, 10-, 12-, AND 16-MINUTE DURATION

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1. GENERAL DESCRIPTION

The ISD4004 ChipCorder® series provides high-quality, 3-volt, single-chip record/playback solutions for 8- to 16-minute messaging applications ideally for cellular phones and other portable products. The CMOS-based devices include an on-chip oscillator, anti-aliasing filter, smoothing filter, AutoMute® feature, audio amplifier, and high density multilevel Flash memory array. The ISD4004 series is designed to be used in a microprocessor- or microcontroller-based system. Address and control are accomplished through a Serial Peripheral Interface (SPI) or Microwire Serial Interface to minimize pin count

Recordings are stored into the on-chip Flash memory cells, providing zero-power message storage. This unique single-chip solution utilizes Nuvoton's patented multilevel storage technology. Voice and audio signals are directly stored onto memory array in their natural form, providing high-quality voice reproduction.

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2. FEATURES

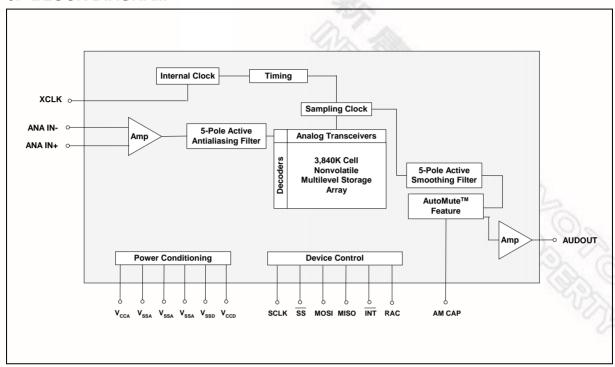
- Single-chip voice record/playback solution
- · Single 3 volt supply
- Low-power consumption
 - Operating current:
 - $I_{CC_Play} = 15 \text{ mA (typical)}$
 - I_{CC Rec} = 25 mA (typical)
 - Standby current:
 - $I_{CC_Standby} = 1 \mu A \text{ (typical)}$
- Duration: 8, 10, 12, and 16 minutes
- High-quality, natural voice/audio reproduction
- AutoMute feature provides background noise attenuation
- · No algorithm development required
- Microcontroller SPI or Microwire[™] Serial Interface
- · Fully addressable to handle multiple messages
- · Non-volatile message storage
- 100K record cycles (typical)
- 100-year message retention (typical)
- · On-chip oscillator
- Power-down feature to reduce power consumption
- · Available in die, PDIP, SOIC, and TSOP
- · Packaged type: Lead-Free
- Temperature:
 - Commercial (die): 0°C to +50°C
 - Commercial (packaged units): 0°C to +70°C
 - Industrial (packaged units): -40°C to +85°C

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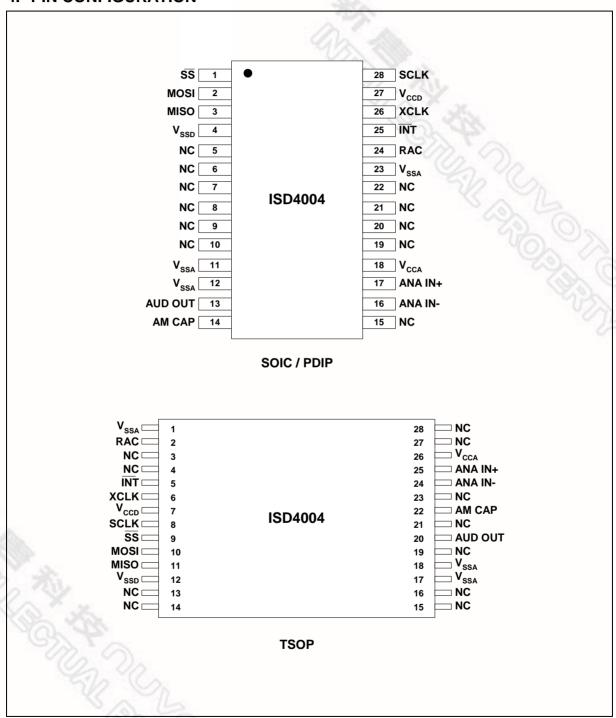
1 -



3. BLOCK DIAGRAM



4. PIN CONFIGURATION





5. PIN DESCRIPTION

PIN NAME	PIN NO.		FUNCTION	
	SOIC / PDIP	TSOP		
SS	1	9	Slave Select : This input, when LOW, will select the ISD4004 device.	
MOSI	2	10	Master Out Slave IN : This is the serial input to the ISD4004 device when it is configured as slave. The master microcontroller places data on the MOSI line one half-cycle before the rising edge of SCLK for clocking into the device.	
MISO	3	11	Master In Slave Out : This is the serial output of the ISD4004 device. This output goes into a high-impedance state if the device is not selected.	
V _{SSA} / V _{SSD}	11, 12, 23 / 4	1, 17, 18 / 12	Ground : The ISD4004 series utilizes separate analog and digital ground busses. The analog ground (V_{SSA}) pins should be tied together as close as possible and connected through a low-impedance path to power supply ground. The digital ground (V_{SSD}) pin should be connected through a separate low-impedance path to power supply ground. These ground paths should be large enough to ensure that the impedance between the V_{SSA} pins and the V_{SSD} pin is less than 3 Ω . The backside of the die is connected to V_{SS} through the substrate. For chip-on-board design, the die attach area must be connected to V_{SS} or left floating.	
NC	5-10, 15, 19-22	3, 4, 13- 16, 19, 21, 23, 27, 28	Not connected	
AUD OUT [1]	13	20	Audio Output : This pin provides an audio output of the stored data and is recommended be AC coupled. It is capable of driving a 5 K Ω impedance R _{EXT} .	

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^[1] The AUD OUT pin is always at 1.2 volts when the device is powered up. When in playback, the output buffer connected to this pin can drive a load as small as 5 K Ω . When in record, a built-in resistor connects AUD OUT to the internal 1.2-volt analog ground supply. This resistor is approximately 850 K Ω , but will vary somewhat according to the sample rate of the device. This relatively high impedance allows this pin to be connected to an audio bus without loading it down.

PIN NAME	PIN	NO.	FUNCTION
	SOIC / PDIP	TSOP	
AM CAP	14	22	AutoMute TM Feature: The AutoMute feature only applies for playback operation and helps to minimize noise (with 6 dB of attenuation) when there is no signal (i.e. during periods of silence). A 1 μF capacitor to ground is recommended to connect to the AM CAP pin.
			This capacitor becomes a part of an internal peak detector which senses the signal amplitude. This peak level is compared to an internally set threshold to determine the AutoMute trip point. For large signals, the AutoMute attenuation is set to 0 dB automatically but 6 dB of attenuation occurs for silence. The 1 µF capacitor also affects the rate at which the AutoMute feature changes with the signal amplitude (or the attack time).
			The AutoMute feature can be disabled by connecting the AM CAP pin directly to V_{CCA} .
ANA IN-	16	24	Inverting Analog Input: This pin transfers the signal into the device during recording via differential-input mode.
			In this differential-input mode, a 16 mVp-p maximum input signal should be capacitively coupled to ANA IN- for optimal signal quality, as shown in Figure 1: ANA IN Modes. This capacitor value should be equal to that used on ANA IN+ pin. The input impedance at ANA IN- is normally 56 K Ω .
			In the single-ended mode, ANA IN- should be capacitively coupled to $V_{\rm SSA}$ through a capacitor equal to that used on the ANA IN+ pin.
ANA IN+	17	25	Non-Inverting Analog Input : This pin is the non-inverting analog input that transfers the signal to the device for recording. The analog input amplifier can be driven single ended or differentially.
			In the single-ended input mode, a 32 mVp-p (peak-to-peak) maximum signal should be capacitively connected to this pin for optimal signal quality. The external capacitor associated with ANA IN+ together with the 3 K Ω input impedance are selected to give cutoff at the low frequency end of the voice passband.
	20		In the differential-input mode, the maximum input signal at ANA IN+ should be 16 mVp-p capacitively coupled for optimal signal quality. The circuit connections for the two modes are shown in Figure 1.

PIN NAME	PIN	I NO.	FUNCTION
	SOIC / PDIP	TSOP	
V _{CCA} / V _{CCD}	18 / 27	26 / 7	Supply Voltage: To minimize noises, the analog and digital circuits in the ISD4004 devices use separate power busses. These +3V busses are brought out to separate pins and should be tied together as close to the supply as possible. In addition, these supplies should be decoupled as close to the package as possible.
RAC	24	2	Row Address Clock: This is an open drain output that provides the signal of a ROW with a 200 ms period for 8 KHz sampling frequency. (This represents a single row of memory.) This signal stays HIGH for 175 ms and stays LOW for 25 ms when it reaches the end of a row.
			The RAC pin stays HIGH for 109.37 µsec and stays LOW for 15.63 µsec in Message Cueing mode (see Message Cueing section for detailed description). Refer to the AC Parameters table for RAC timing information at other sample rates.
			When a record command is first initiated, the RAC pin remains HIGH for an extra T_{RACL} period. This is due to the need of loading the internal sample and hold circuits in the device. This pin can be used for message management techniques.
			A pull-up resistor is required to connect this pin to other device.
INT	25	5	Interrupt: This is an open drain output pin. This pin goes LOW and stays LOW when an Overflow (OVF) or End of Message (EOM) marker is detected. Each operation that ends with an EOM or OVF will generate an interrupt. The interrupt will be cleared the next time an SPI cycle is initiated. The interrupt status can also be read by an R _{INT} instruction.
The Street			A pull-up resistor is required to connect this pin to other device.
			Overflow Flag (OVF) – The Overflow flag indicates that the end of memory has been reached during a record or playback operation.
	20.		End of Message (EOM) – The End of Message flag is set only during playback operation when an EOM is found. There are eight EOM flag position options per row.

PIN NAME	PIN	I NO.		FUNCTION		
	SOIC / PDIP	TSOP				
XCLK	26	6	the factory with an centered to ±1 percentered to ±1 percentered to entire commercial ranges. The internal over the industrial regulated power su temperature range percentered to the content of the con	n internal samplent of specifical a variation of ± temperature all clock has a — temperature arupply is recomparts. If greater present of specifical specifical arts.	oling clock frequency tion. The frequency 2.25 percent over nd operating volta 6/+4 percent tolerand voltage ranges, mended for industrecision is required,	ency y is the age nce . A trial
			Part Number Sample Rate Required Clock			
			ISD4004-08M	8.0 kHz	1024 kHz	
			ISD4004-10M	6.4 kHz	819.2 kHz	6
			ISD4004-12M	5.3 kHz	682.7 kHz	110
			ISD4004-16M	4.0 kHz	512 kHz	2
			These recommended because the anti-ali Otherwise, aliasing put differs from the one input clock is not crit by two. If the XCL connected to ground	asing and smoo problems can or recommended. ical, as the clock K is not used	othing filters are fix ocur if the sample r The duty cycle on is immediately divid	ced. rate the ded
SCLK	28	8	Serial Clock: This is It is generated microcontoller) and i in and out of the dev respectively. Data is edge of SCLK and edge of SCLK.	by the mast s used to synchr rice through the latched into the	er device (typic onize the data trans MOSI and MISO lin ISD4004 on the ris	cally sfer nes, sing



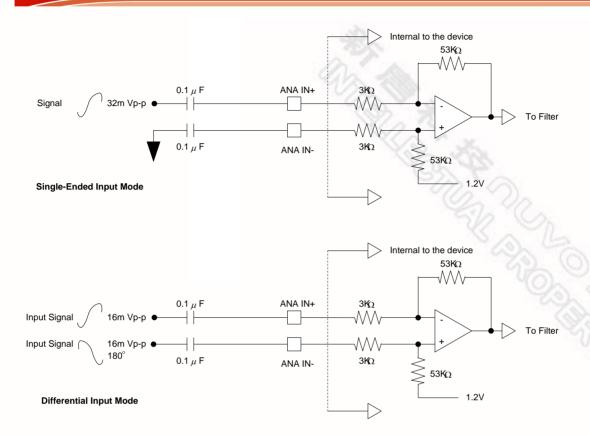


FIGURE 1: ISD4004 SERIES ANA IN MODES

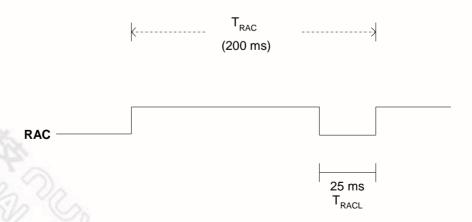


FIGURE 2: RAC TIMING WAVEFORM DURING NORMAL OPERATION

(example of 8KHz sampling rate)

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6. FUNCTIONAL DESCRIPTION

6.1. DETAILED DESCRIPTION

Audio Quality

The Nuvoton's ISD4004 ChipCorder[®] series is offered at 8.0, 6.4, 5.3 and 4.0 kHz sampling frequencies, allowing the user a choice of speech quality options. Increasing the sampling frequency will produce better sound quality, but affects duration. Please refer to Table 1: Product Summary for details.

Analog speech samples are stored directly into on-chip non-volatile memory without the digitization and compression associated with other solutions. Direct analog storage provides higher quality reproduction of voice, music, tones, and sound effects than other solid-state solutions.

Duration

The ISD4004 Series is a single-chip solution with 8-, 10-, 12-, and 16-minute duration.

TABLE 1: PRODUCT SUMMARY OF ISD4004 SERIES

Part Number	Duration (Minutes)	Sample Rate (kHz)	Typical Filter Pass Band (kHz) *
ISD4004-08M	8	8.0	3.4
ISD4004-10M	10	6.4	2.7
ISD4004-12M	12	5.3	2.3
ISD4004-16M	16	4.0	1.7

^{*} This is the –3dB point. This parameter is not checked during production testing and may vary due to process variations and other factors. Therefore, the customer should not rely upon this value for testing purposes.

Flash Storage

The ISD4004 series utilizes on-chip Flash memory, providing zero-power message storage. The message is retained for up to 100 years typically without power. In addition, the device can be rerecorded typically over 100,000 times.

Memory Architecture

The ISD4004 series contains a total of 3,840K Flash memory cells, which is organized as 2,400 rows of 1,600 cells each. The address bits (A0-A15) are used to access various rows for multiple messages of different durations.

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Microcontroller Interface

A four-wire (SCLK, MOSI, MISO & SS) SPI interface is provided for controlling and addressing functions. The ISD4004 is configured to operate as a peripheral slave device, with a microcontrollerbased SPI bus interface. Read and write operations are controlled through this SPI interface. An interrupt signal (INT) and internal read only Status Register are provided for handshake purposes.

Programming

The ISD4004 series is also ideal for playback-only applications, where single- or multiple-messages playback is controlled through the SPI port. Once the desired message configuration is created, duplicates can easily be generated via a programmer.

6.2. SERIAL PERIPHERAL INTERFACE (SPI) DESCRIPTION

The ISD4004 series operates via SPI serial interface with the following protocol.

First, the data transfer protocol assumes that the microcontroller's SPI shift registers are clocked on the falling edge of the SCLK. However, for the ISD4004, the protocols are as follows:

- 1. All serial data transfers begin with the falling edge of SS pin.
- SS is held LOW during all serial communications and held HIGH between instructions.
- 3. Data is clocked in on the rising edge of the SCLK signal and clocked out on the falling edge of the SCLK signal, with LSB first.
- 4. Playback and record operations are initiated when the device is enabled by asserting the SS pin LOW, shifting in an opcode and an address data to the ISD4004 device (refer to the Opcode Summary in the following page).
- 5. The opcodes contain <16 address bits> and <8 control bits>.
- 6. Each operation that ends with an EOM or Overflow will generate an interrupt. The Interrupt will be cleared the next time a SPI cycle is initiated.
- As Interrupt data is shifted out of the MISO pin, while address and control data are simultaneously shifted into the MOSI pin. Care should be taken such that the data shifted in is compatible with current system operation. Because it is possible to read an interrupt data and start a new operation within the same SPI cycle.
- An operation begins with the RUN bit set and ends with the RUN bit reset.
- All operations begin after the rising edge of SS.

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6.2.1 OPCODES

The available Opcodes are summarized as follows:

TABLE 2: OPCODE SUMMARY

Instructions	Op(Codes		Descriptions
	Address (16 bits) <a0 a15="" –=""></a0>	Control bits (8 bits) XXX C0 C1 C2 C3 C4		
POWERUP	<xxxxxx></xxxxxx>	XXX 0 0 1 0	0	Power-Up: Device will be ready for an operation after T_{PUD} .
SETPLAY	<a0 a15="" –=""></a0>	XXX 0 0 1 1	1	Initiates playback from address <a0-a15>.</a0-a15>
PLAY	<xxxxxx></xxxxxx>	XXX 0 1 1 1	1	Playback from the current address (until EOM or OVF).
SETREC	<a0 a15="" –=""></a0>	XXX 0 0 1 0	1	Initiates a record operation from address <a0-a15>.</a0-a15>
REC	<xxxxxx></xxxxxx>	XXX 0 1 1 0	1	Records from current address until OVF is reached or Stop command is sent.
SETMC	<a0 a15="" –=""></a0>	XXX 1 0 1 1	1	Initiates Message Cueing (MC) from address <a0-a15>.</a0-a15>
MC ^[1]	<xxxxxx></xxxxxx>	XXX 1 1 1 1	1	Performs a Message Cueing from current location. Proceeds to the end of message (EOM) or enters OVF condition if no more messages are present.
STOP	<xxxxxx></xxxxxx>	XXX 0 1 1 X	0	Stops the current operation.
STOPPWRDN	<xxxxxx></xxxxxx>	XXX X 1 0 X	0	Stops the current operation and enters into standby (power-down) mode.
RINT [2]	<xxxxxx></xxxxxx>	XXX 0 1 1 X	0	Read Interrupt status bits: Overflow and EOM.

Notes:

C0 = Message cueing

C1 = Ignore address bit

C2 = Master power control

C3 = Record or playback operation

C4 = Enable or disable an operation

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^[1] Message Cueing can be selected only at the beginning of a playback operation.

As the Interrupt data is shifted out of the ISD4004, control and address data are being shifted in. Care should be taken such that the data shifted in is compatible with current system operation. It is possible to read interrupt data and start a new operation at the same time. See Figures 5 - 8 for references.

6.2.2 SPI Diagrams

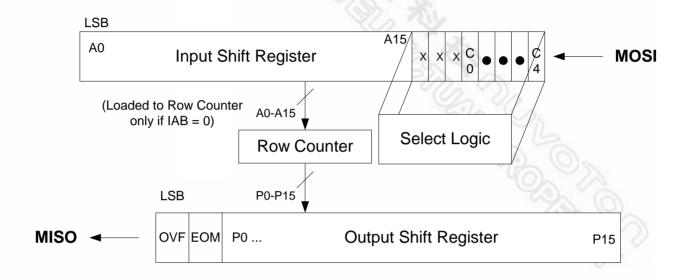
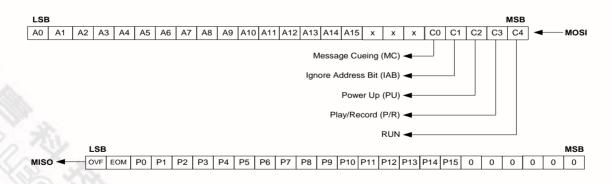


FIGURE 3: SPI INTERFACE SIMPLIFIED BLOCK DIAGRAM

The following diagram describes the SPI port and the control bits associated with it.



Notes: 1. For MOSI, LSB is the 1st bit shifted into the ISD4004.

2. For MISO, LSB is the 1st bit shifted out from the ISD4004.

FIGURE 4: SPI PORT

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6.2.3 SPI Control and Output Registers

The SPI control register provides control of individual function such as play, record, message cueing, power-up, power-down, start, stop and ignore address pointer operations.

TABLE 3: SPI CONTROL REGISTERS

Control Bit	Control Register	Bit	Device Function
C0	MC		Message Cueing function
	=	: 1	Enable Message Cueing
	=	: 0	Disable Message Cueing
C1	IAB ^[1]		Ignore Address bit
	=	: 1	Ignore input address register (A0-A15)
	=	: 0	Use the input address register (A0-A15)
C2	PU		Power Up
	=	: 1	Power-Up
	=	: 0	Power-Down
C3	P/R		Playback or Record
	=	■ 1	Play
	=	0	Record
C4	RUN		Enable or Disable an operation
	=	: 1	Start
	=	: 0	Stop
Address Bits	A0-A15		Input address register

TABLE 4: SPI OUTPUT REGISTERS

Output Bits	Description
OVF	Overflow
EOM	End-of-Message
P0-P15	Output of the row pointer register

^[1] When IAB (Ignore Address Bit) is set to 0, a playback or record operation starts from address (A0-A15). For consecutive playback or record, IAB should be changed to a 1 before the end of that row (see RAC timing). Otherwise the ISD4004 will repeat the operation from the same row address. For memory management, the Row Address Clock (RAC) signal and IAB can be used to move around the memory segments.

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Message Cueing

Message cueing (MC) allows the user to skip through messages, without knowing the actual physical location of the messages. It will stop when an EOM marker is reached. Then, the internal address counter will point to the next message. Also, it will enter into OVF condition when it reaches the end of memory. In this mode, the messages are skipped 1,600 times faster than the normal playback mode.

Power-Up Sequence

The ISD4004 will be ready for an operation after power-up command is sent and followed by the T_{PUD} timing (25 ms for 8 KHz sampling rate). Refer to the AC timing table for other T_{PUD} values with respect to different sampling rates.

The following sequences are recommended for optimized Record and Playback operations.

Record Mode

- 1. Send POWERUP command.
- 2. Wait T_{PUD} (power-up delay).
- 3. Send POWERUP command.
- 4. Wait 2 x T_{PUD} (power-up delay).
- 5. a). Send SETREC command with address xx, or
 - b). Send REC command (recording from current location).
- 6. Send STOP command to stop recording.
- 7. Wait T_{STOP/PAUSE}.

For 3 & 4), please refer to Apps Brief 39A: recorded pop elimination in the ISD4000 series.

For 5.a), the device will start recording at address xx and will generate an interrupt when an overflow (end of memory array) is reached, if no STOP command is sent before that. Then, it will automatic stop recording operation.

Playback Mode

- 1. Send POWERUP command
- 2. Wait T_{PUD} (power-up delay)
- 3. a). Send SETPLAY command with address xx, or
 - b). Send PLAY command (playback from current location).
- 4. a). Send STOP command to halt the playback operation, or
 - b). Wait for playback operation to stop automatically, when an EOM or OVF is reached.
- 5. Wait T_{STOP/PAUSE}.

For 3.a), the device will start playback at address xx and it will generate an interrupt when an EOM or OVF is reached. It will then stop playback operation.

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7. TIMING DIAGRAMS

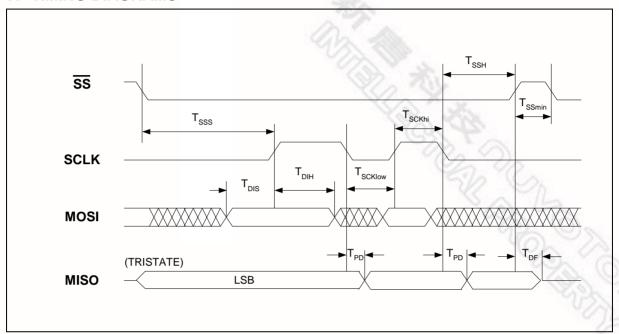


FIGURE 5: TIMING DIAGRAM

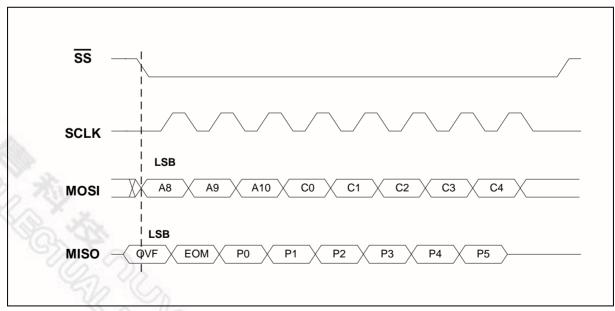


FIGURE 6: 8-BIT COMMAND FORMAT

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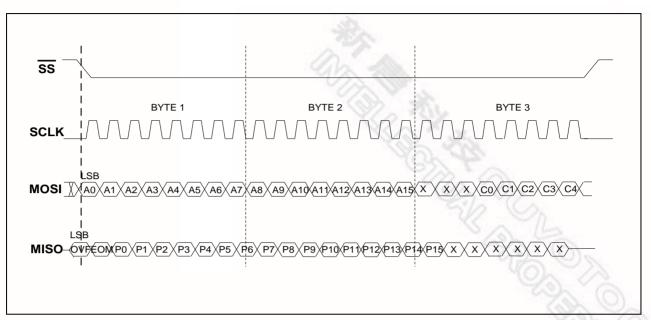


FIGURE 7: 16-BIT COMMAND FORMAT

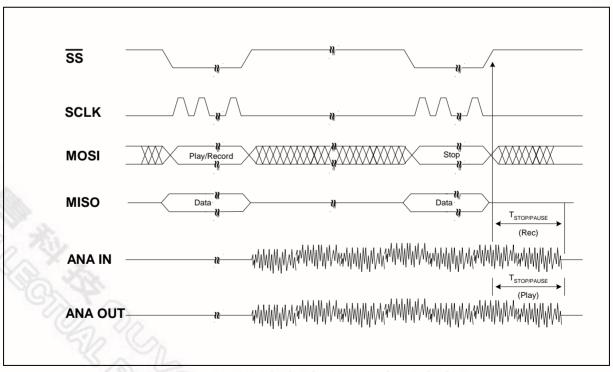


FIGURE 8: PLAYBACK/RECORD AND STOP CYCLE

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8. ABSOLUTE MAXIMUM RATINGS

TABLE 5: ABSOLUTE MAXIMUM RATINGS (PACKAGED PARTS)

CONDITIONS	VALUES
Junction temperature	150°C
Storage temperature range	-65°C to +150°C
Voltage applied to any pin	(V _{SS} -0.3V) to (V _{CC} +0.3V)
Voltage applied to any pin (Input current limited to ±20mA)	$(V_{SS} - 1.0V)$ to $(V_{CC} + 1.0V)$
Voltage applied to MOSI, SCLK, and SS pins (Input current limited to ±20mA)	(V _{SS} –1.0V) to 5.5V
Lead temperature (soldering – 10 seconds)	300°C
V _{CC} – V _{SS}	-0.3V to +7.0V

TABLE 6: ABSOLUTE MAXIMUM RATINGS (DIE)

CONDITIONS	VALUES
Junction temperature	150°C
Storage temperature range	-65°C to +150°C
Voltage applied to any pad	$(V_{SS} - 0.3V)$ to $(V_{CC} + 0.3V)$
Voltage applied to any pad (Input current limited to ± 20 mA)	$(V_{SS} - 1.0V)$ to $(V_{CC} + 1.0V)$
Voltage applied to MOSI, SCLK, and SS pins (Input current limited to ±20mA)	(V _{SS} –1.0V) to 5.5V
$V_{CC} - V_{SS}$	-0.3V to +7.0V

Note: Stresses above those listed may cause permanent damage to the device. Exposure to the absolute maximum ratings may affect device reliability and performance. Functional operation is not implied at these conditions.



8.1. OPERATING CONDITIONS

TABLE 7: OPERATING CONDITIONS (PACKAGED PARTS)

CONDITIONS	VALUES
Commercial operating temperature range (Case temperature)	0°C to +70°C
Industrial operating temperature (Case temperature)	-40°C to +85°C
Supply voltage (V _{CC}) [1]	+2.7V to +3.3V
Ground voltage (V _{SS}) [2]	0V

TABLE 8: OPERATING CONDITIONS (DIE)

CONDITIONS	VALUES
Commercial operating temperature range	0°C to +50°C
Supply voltage (V _{CC}) [1]	+2.7V to +3.3V
Ground voltage (V _{SS}) [2]	0V

 $^{^{[1]}}$ $V_{CC} = V_{CCA} = V_{CCD}$

 $^{^{[2]}}$ $V_{SS} = V_{SSA} = V_{SSD}$



9. ELECTRICAL CHARACTERISTICS

9.1. PARAMETERS FOR PACKAGED PARTS

TABLE 9: DC PARAMETERS

PARAMETERS	SYMBOLS	MIN ^[2]	TYP ^[1]	MAX ^[2]	UNITS	CONDITIONS
Input Low Voltage	V _{IL}			V _{CC} x 0.2	V	
Input High Voltage	V _{IH}	V _{CC} x 0.8		627	V	
Output Low Voltage	V _{OL}			0.4	_ V	I _{OL} = 10 μA
RAC, INT Output Low Voltage	V _{OL1}			0.4	V	I _{OL} = 1 mA
Output High Voltage	V _{OH}	V _{CC} - 0.4			V	I _{OH} = -10 μA
Operating Current	I _{CC}					50 C
- Playback			15	30	mA	R _{EXT} = ∞ ^[3]
- Record			25	40	mA	R _{EXT} = ∞ ^[3]
Standby Current	I _{SB}		1	10	μΑ	[3] [4]
Input Leakage Current	I _{IL}			±1	μA	20
MISO Tri-State Current	I _{HZ}		1	10	μΑ	
Output Load Impedance	R _{EXT}	5			ΚΩ	
ANA IN+ Input Resistance	R _{ANA IN+}	2.2	3.0	3.8	ΚΩ	
ANA IN- Input Resistance	R _{ANA IN-}	40	56	71	ΚΩ	
ANA IN+ or ANA IN- to AUD OUT Gain	A _{ARP}		23		dB	32 mVpp 1 KHz sinewave input ^[5]

Notes:

Typical values @ $T_A = 25$ °C and $V_{CC} = 3.0$ V.

All Min/Max limits are guaranteed by Nuvoton via electronical testing or characterization. Not all specifications are 100 percent tested.

 V_{CCA} and V_{CCD} connected together.

 $[\]overline{SS} = V_{CCA} = V_{CCD}$, XCLK = MOSI = $V_{SSA} = V_{SSA}$ and all other pins floating.

^[5] Measured with AutoMute feature disabled.



TABLE 10: AC PARAMETERS (Packaged Parts)

CHARACTERISTIC	SYMBOLS	MIN ^[2]	TYP ^[1]	MAX ^[2]	UNITS	CONDITIONS
Sampling Frequency	Fs	12	20 %	200		[6]
ISD4004-08M			8.0	2000	KHz	[5]
ISD4004-10M		57	6.4	£111111	KHz	[5]
ISD4004-12M			5.3	1200	KHz	[5]
ISD4004-16M			4.0	5 10	KHz	[5]
Filter Pass Band	F _{CF}		76.0	10.75	33/	
ISD4004-08M			3.4	(()	KHz	3 dB Roll-Off Point[3][7]
ISD4004-10M			2.7	100	KHz	3 dB Roll-Off Point ^{[3][7]}
ISD4004-12M			2.3	177	KHz	3 dB Roll-Off Point ^{[3][7]}
ISD4004-16M			1.7	163	KHz	3 dB Roll-Off Point ^{[3][7]}
Record Duration	T _{REC}			7	772	(23V
ISD4004-08M	- NEC		8		min	[6]
ISD4004-10M			10		min	[6]
ISD4004-12M			12		min	[6]
ISD4004-16M			16		min	[6]
Playback Duration	T _{PLAY}		10		111111	(0)
ISD4004-08M	PLAY		8		min	[6]
ISD4004-00W			10		min	[6]
ISD4004-10M			12		min	[6]
ISD4004-12M ISD4004-16M			16		min	[6]
Power-Up Delay	T _{PUD}		10		111111	
ISD4004-08M	PUD		25		maaa	(17:41)
ISD4004-06M ISD4004-10M			31.25		msec	
					msec	0/
ISD4004-12M			37.5		msec	
ISD4004-16M			50		msec	
Stop or Pause in Record or Play	T _{STOP} or T _{PAUSE}					
ISD4004-08M			50		msec	
ISD4004-10M			62.5		msec	
ISD4004-12M			75		msec	
ISD4004-16M			100		msec	
RAC Clock Period	T _{RAC}					[10]
ISD4004-08M			200		msec	[10]
ISD4004-10M			250		msec	
ISD4004-12M			300		msec	[10]
ISD4004-16M			400		msec	[10]
RAC Clock Low Time	T _{RACL}					
ISD4004-08M			25		msec	
ISD4004-10M			31.25		msec	
ISD4004-12M			37.5		msec	
ISD4004-16M			50		msec	
RAC Clock Period in Message	T _{RACM}					
Cueing Mode						
ISD4004-08M			125		µsec	
ISD4004-10M			156.3		µsec	
ISD4004-12M			187.5		µsec	
ISD4004-16M			250		µsec	
RAC Clock Low Time in	T _{RACML}					
Message Cueing Mode						
ISD4004-08M			15.63		µsec	
ISD4004-10M			19.53		µsec	
ISD4004-12M			23.44		µsec	
ISD4004-16M			31.25		µsec	
Total Harmonic Distortion	THD		1	2	%	32 mVpp 1 KHz
35 ~ 1						sinewave input [11]
ANA IN Input Voltage	V _{IN}			32	mV	Peak-to-Peak [4] [8] [9]

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Notes:

- Typical values @ $T_A = 25$ °C, $V_{CC} = 3.0$ V and timing measurement at 50% of Vcc level.
- [2] All Min/Max limits are guaranteed by Nuvoton via electrical testing or characterization. Not all specifications are 100 percent tested.
- [3] Low-frequency cutoff depends upon the value of external capacitors (see Pin Descriptions)
- [4] Single-ended input mode. In the differential input mode, V_{IN} maximum for ANA IN+ and ANA IN- is 16 mVp-p.
- Sampling Frequency can vary as much as ±2.25 percent over the commercial temperature and voltage ranges, and –6/+4 percent over the industrial temperature and voltage ranges. For greater stability, an external clock can be utilized (see Pin Descriptions)
- Playback and Record Duration can vary as much as ±2.25 percent over the commercial temperature and voltage ranges, and –6/+4 percent over the industrial temperature and voltage ranges. For greater stability, an external clock can be utilized (see Pin Descriptions)
- [7] Filter specification applies to the antialiasing filter and the smoothing filter. Therefore, from input to output, expect a 6 dB drop by nature of passing through both filters.
- The typical output voltage will be approximately 450 mVp-p with V_{IN} at 32 mVp-p.
- [9] For optimal signal quality, this maximum limit is recommended.
- When a record command is sent, $T_{RAC} = T_{RAC} + T_{RACL}$ on the first row address.
- [11] Measured with AutoMute feature disabled.

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9.2. PARAMETERS FOR DIE

TABLE 11: DC PARAMETERS

PARAMETERS [6]	SYMBOLS	MIN ^[2]	TYP ^[1]	MAX ^[2]	UNITS	CONDITIONS
Input Low Voltage	V _{IL}		(II)	V _{CC} x 0.2	V	
Input High Voltage	V _{IH}	V _{CC} x 0.8	73	2 X	V	
Output Low Voltage	V _{OL}			0.4	V	I _{OL} = 10 μA
RAC, INT Output Low Voltage	V _{OL1}			0.4	V	I _{OL} = 1 mA
Output High Voltage	V _{OH}	V _{CC} - 0.4		- 3	V	I _{OH} = -10 μA
Operating Current	I _{cc}				10/0	1
-Playback			15	30	mA	R _{EXT} = ∞ ^[3]
-Record			25	40	mA	R _{EXT} = ∞ ^[3]
Standby Current	I _{SB}		1	10	μA	[3] [4]
Total Harmonic Distortion	THD		1	2	%	32 mVpp 1 KHz sinewave input [5]
ANA IN+ or ANA IN- to AUD OUT Gain	A _{ARP}		23		dB	32 mVpp 1 KHz sinewave input ^[5]

Notes:

- Typical values @ $T_A = 25$ °C and $V_{CC} = 3.0$ V. Sampling Frequency can vary as much as ± 2.25 percent over the commercial temperature and voltage ranges.
- All Min/Max limits are guaranteed by Nuvoton via electrical testing or characterization. Not all specifications are 100 percent tested.
- ^[3] V_{CCA} and V_{CCD} connected together.
- SS = $V_{CCA} = V_{CCD}$, XCLK = MOSI = $V_{SSA} = V_{SSA}$ and all other pins floating.
- [5] Measured with AutoMute feature disabled.
- The test coverage for die is limited to room temperature testing. The test conditions may differ from that of packaged parts.



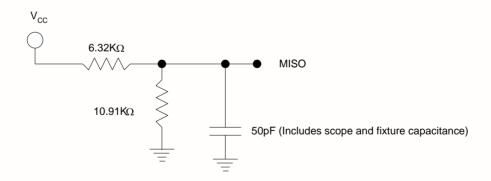
9.3. SPI AC PARAMETERS

TABLE 12: AC PARAMETERS^[1]

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	CONDITIONS
SS Setup Time	T _{SSS}	500		dik	nsec	
SS Hold Time	T _{SSH}	500	K	OX.	nsec	
Data in Setup Time	T _{DIS}	200		100	nsec	
Data in Hold Time	T _{DIH}	200		477	nsec	
Output Delay	T _{PD}			500	nsec	5
Output Delay to HighZ [2]	T _{DF}			500	nsec	7/6
SS HIGH	T _{SSmin}	1			µsec	50
SCLK High Time	T _{SCKhi}	400			nsec	000
SCLK Low Time	T _{SCKlow}	400			nsec	J. 10.
CLK Frequency	F_0			1,000	KHz	435

Notes:

- Typical values @ $T_A = 25$ °C, $V_{CC} = 3.0$ V and timing measurement at 50% of Vcc level.
- [2] Tri-state test condition.





10. TYPICAL APPLICATION CIRCUIT

These application examples are for illustration purposes only. Nuvoton makes no representation or warranty that such application will be suitable for production.

Make sure all bypass capacitors are as close as possible to the package.

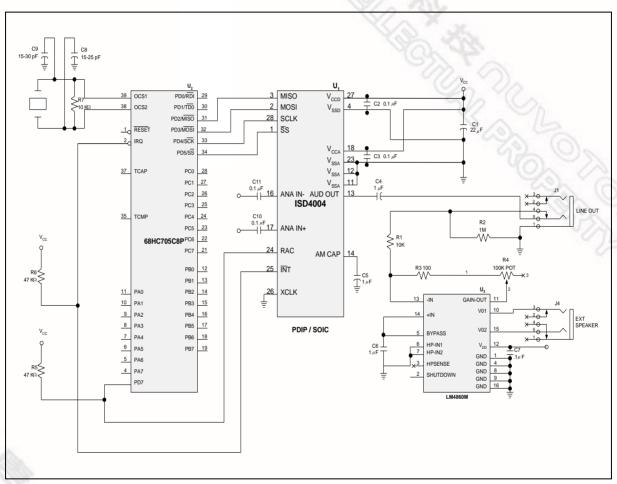


FIGURE 9: APPLICATION EXAMPLE USING SPI

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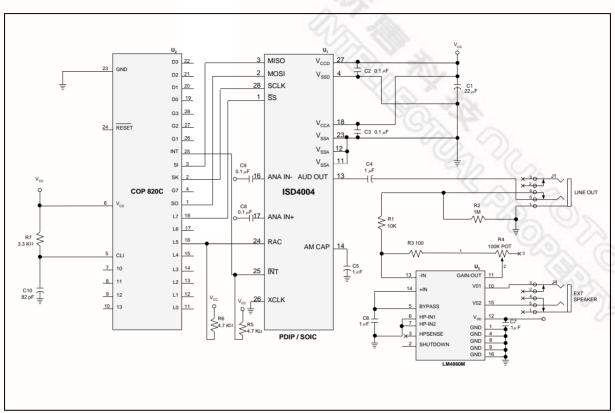


FIGURE 10: APPLICATION EXAMPLE USING MICROWIRE

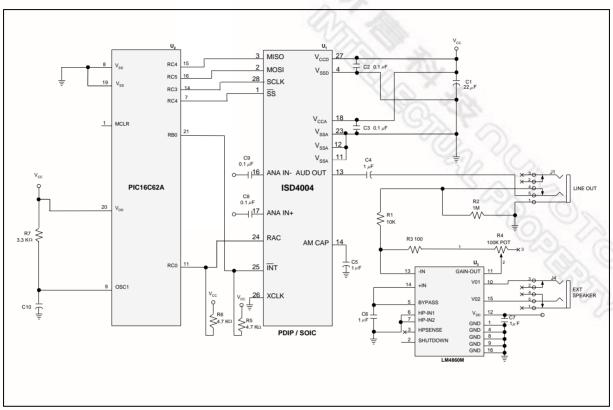
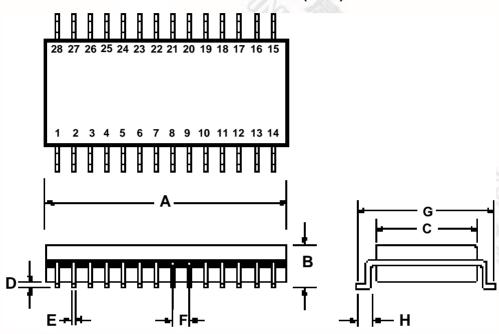


FIGURE 11: APPLICATION EXAMPLE USING SPI PORT ON MICROCONTROLLER

11. PACKAGING AND DIE INFORMATION

11.1. 28-LEAD 300-MIL PLASTIC SMALL OUTLINE IC (SOIC)

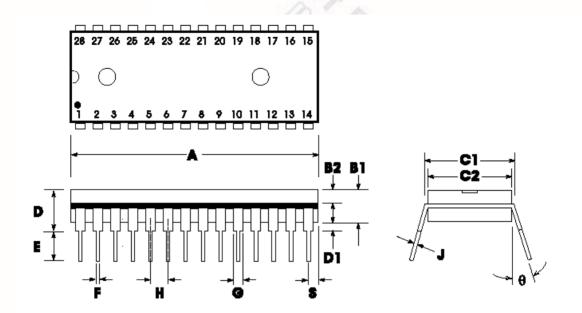


		INCHES		N	MILLIMETERS			
	Min	Nom	Max	Min	Nom	Max		
Α	0.701	0.706	0.711	17.81	17.93	18.06		
В	0.097	0.101	0.104	2.46	2.56	2.64		
С	0.292	0.296	0.299	7.42	7.52	7.59		
D	0.005	0.009	0.0115	0.127	0.22	0.29		
Е	0.014	0.016	0.019	0.35	0.41	0.48		
F		0.050			1.27			
G	0.400	0.406	0.410	10.16	10.31	10.41		
ωH	0.024	0.032	0.040	0.61	0.81	1.02		

Note: Lead coplanarity to be within 0.004 inches.

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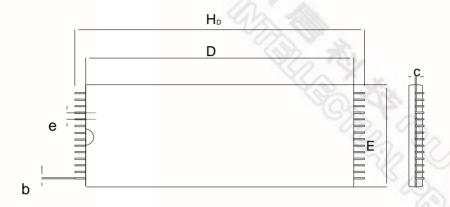
11.2. 28-LEAD 600-MIL PLASTIC DUAL INLINE PACKAGE (PDIP)



		INCHES		N	IILLIMETER:	S
	Min	Nom	Max	Min	Nom	Max
Α	1.445	1.450	1.455	36.70	36.83	36.96
B1		0.150			3.81	
B2	0.065	0.070	0.075	1.65	1.78	1.91
C1	0.600		0.625	15.24		15.88
C2	0.530	0.540	0.550	13.46	13.72	13.97
D			0.19			4.83
D1	0.015			0.38		
S.E	0.125		0.135	3.18		3.43
F	0.015	0.018	0.022	0.38	0.46	0.56
G	0.055	0.060	0.065	1.40	1.52	1.62
C) H	7,	0.100			2.54	
	0.008	0.010	0.012	0.20	0.25	0.30
S	0.070	0.075	0.080	1.78	1.91	2.03
q	0°	6	15°	0°		15°



11.3. 28-LEAD 8x13.4mm PLASTIC THIN SMALL OUTLINE PACKAGE (TSOP) TYPE 1 - IQC



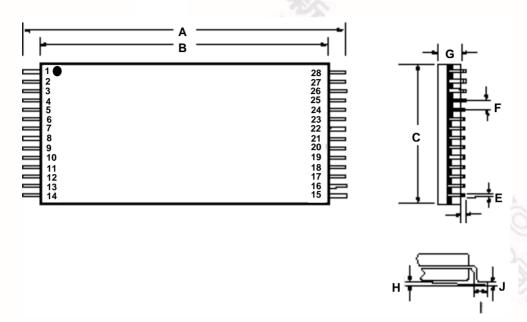


	Dimen	sion in	Inches	Dime	Dimension in mm			
Symbol	Min.	Nom.	Max.	Min.	Nom.	Max.		
Α	_		0.047	_	_	1.20		
A 1	0.002		0.006	0.05		0.15		
A 2	0.035	0.040	0.041	0.95	1.00	1.05		
b	0.007	0.008	0.011	0.17	0.20	0.27		
С	0.004	0.006	0.008	0.10	0.15	0.21		
D	0.461	0.465	0.469	11.70	11.80	11.90		
Е	0.311	0.315	0.319	7.90	8.00	8.10		
H□	0.520	0.528	0.536	13.20	13.40	13.60		
е	_	0.022			0.55			
L	0.020	0.024	0.028	0.50	0.60	0.70		
L1		0.031			0.80			
Υ	0.000		0.004	0.00		0.10		
θ	0	3	5	0	3	5		

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11.4. 28-LEAD 8x13.4mm PLASTIC THIN SMALL OUTLINE PACKAGE (TSOP) TYPE 1



		INCHES		N	ILLIMETER:	S
	Min	Nom	Max	Min	Nom	Max
Α	0.520	0.528	0.535	13.20	13.40	13.60
В	0.461	0.465	0.469	11.70	11.80	11.90
С	0.311	0.315	0.319	7.90	8.00	8.10
D	0.002		0.006	0.05		0.15
Е	0.007	0.009	0.011	0.17	0.22	0.27
F		0.0217			0.55	
G	0.037	0.039	0.041	0.95	1.00	1.05
Н	0°	3°	6°	0°	3°	6°
I	0.020	0.022	0.028	0.50	0.55	0.70
J	0.004		0.008	0.10		0.21

Note: Lead coplanarity to be within 0.004 inches.



11.5. **DIE INFORMATION**

ISD4004 Series

o Die Dimensions (with scribe line) [1]

X: 166.6 ± 1 mils

Y: $385.0 \pm 1 \text{ mils}$

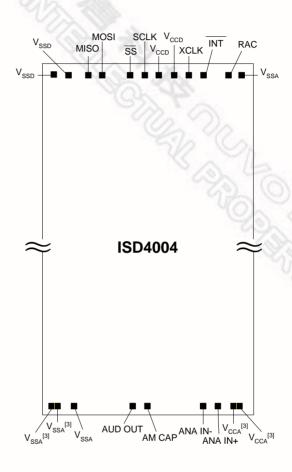
Die Thickness [2]

 11.5 ± 0.5 mils

Pad Opening

Single pad: 90 x 90 microns

Double pad: 180 x 90 microns



Notes:

- The backside of die is internally connected to V_{SS} . It **MUST NOT** be connected to any other potential or damage may occur.
- Die thickness is subject to change, please contact Nuvoton as this thickness may change in the future.
- Double bond is recommended if treated as one pad.

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ISD4004 SERIES PAD COORDINATIONS

(with respect to die center)

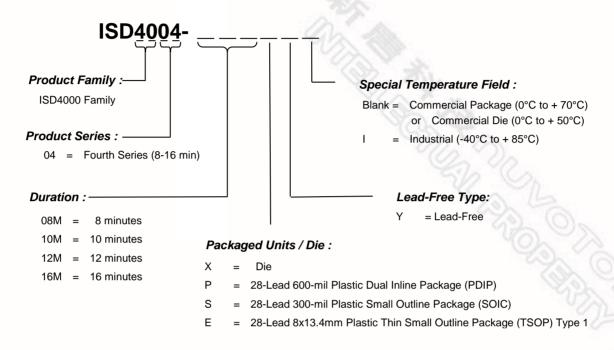
Pad	Pad Description	X Axis (μm)	Y Axis (µm)
V_{SSA}	Analog Ground	1885.2	4623.7
RAC	Row Address Clock	1483.8	4623.7
ĪNT	Interrupt	794.8	4623.7
XCLK	External Clock Input	564.8	4623.7
V _{CCD}	Digital Power Supply	387.9	4623.7
V _{CCD}	Digital Power Supply	169.5	4623.7
SCLK	Slave Clock	-14.7	4623.7
SS	Slave Select	-198.1	4623.7
MOSI	Master Out Slave In	-1063.7	4623.7
MISO	Master In Slave Out	-1325.6	4623.7
V _{SSD}	Digital Ground	-1665.3	4623.7
V _{SSD}	Digital Ground	-1836.9	4623.7
V _{SSA} ^[1]	Analog Ground	-1943.1	-4622.4
V _{SSA} ^[1]	Analog Ground	-1853.1	-4622.4
V _{SSA}	Analog Ground	-1599.9	-4622.4
AUD OUT	Audio Output	281.9	-4622.4
AM CAP	AutoMute	577.3	-4622.4
ANA IN- Inverting Analog Input		1449.3	-4622.4
ANA IN+	Noninverting Analog Input	1603.5	-4622.4
V _{CCA} ^[1]	Analog Power Supply	1853.7	-4622.4
V _{CCA} ^[1]			-4622.4

Note:

Double bond recommended if treated as one pad.



12. ORDERING INFORMATION



When ordering the devices, please refer to the following valid ordering numbers and contact the local Nuvoton Sales Representatives for availability.

Туре	Duration	8 Minutes	8 Minutes		10 Minutes		12 Minutes		16 Minutes	
	Package	Part #	Order #	Part #	Order #	Part #	Order #	Part #	Order #	
	Die	ISD4004-08MX	14408X	ISD4004-10MX	14410X	ISD4004-12MX	I4412X	ISD4004-16MX	I4416X	
	PDIP	ISD4004-08MPY	14408PY	ISD4004-10MPY	I4410PY	ISD4004-12MP	I4412PY	ISD4004-16MPY	I4416PY	
Φ	SOIC	ISD4004-08MSY	14408SY	ISD4004-10MSY	I4410SY	ISD4004-12MS	I4412SY	ISD4004-16MSY	14416SY	
Lead-Free		ISD4004-08MSYI	14408SY 1	ISD4004-10MSYI	14410SYI	ISD4004- 12MSI	14412SYI	ISD4004- 16MSYI	14416SY I	
Lea	TSOP	ISD4004-08MEY	14408EY	ISD4004-10MEY	14410EY	ISD4004-12ME	I4412EY	ISD4004-16MEY	14416EY	
	ik.	ISD4004-08MEYI	14408EY I	ISD4004-10MEYI	14410EYI	ISD4004- 12MEI	14412EYI	ISD4004- 16MEYI	I4416EY I	

For the latest product information, access Nuvoton worldwide website at http://www.Nuvoton-usa.com



13. VERSION HISTORY

VERSION	DATE	DESCRIPTION
0	June 2000	Initial version
1.0	Feb. 2004	Reformat the document.
		Add note for typical filter pass band.
		Add memory architecture description.
		Revise RAC timing parameter for MC.
		Revise AutoMute: playback only.
		Revise SPI, opcodes sections, record & playback steps.
		Rename T _{RACLO} to T _{RACL} .
		Revise A _{ARP} parameter.
		Revise DC & AC parameters tables for die.
		Revise die: (x,y) coordinates.
1.1	Apr. 2005	Add lead-free parts.
		Revise the Ordering information.
		Revise disclaim section.
1.2	Oct. 2005	Revise Packaging information.
1.3	Jul. 2007	Remove the leaded package option
		Remove the extended temperature option
		Update the external clock description
		Revise Ordering Information section
1.31	Oct 31, 2008	Change to Nuvoton logo
		Revise MISO description

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Headquarters

No. 4, Creation Rd. III Science-Based Industrial Park, Hsinchu, Taiwan TEL: 886-3-5770066 FAX: 886-3-5665577 http://www.Nuvoton.com.tw/

Taipei Office

9F, No. 480, Pueiguang Rd. Neihu District Taipei, 114 Taiwan TEL: 886-2-81777168 FAX: 886-2-87153579

Nuvoton Technology Corporation America

2727 North First Street, San Jose, CA 95134, U.S.A. TEL: 1-408-9436666 FAX: 1-408-5441797 http://www.Nuvoton-usa.com/

Nuvoton Technology Corporation Japan

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7F Daini-ueno BLDG. 3-7-18 Shinyokohama Kohokuku, Yokohama, 222-0033 TEL: 81-45-4781881 FAX: 81-45-4781800

Nuvoton Technology (Shanghai) Ltd.

27F, 299 Yan An W. Rd. Shanghai, 200336 China TEL: 86-21-62365999 FAX: 86-21-62356998

Nuvoton Technology (H.K.) Ltd.

Unit 9-15, 22F, Millennium City, No. 378 Kwun Tong Rd., Kowloon, Hong Kong TEL: 852-27513100 FAX: 852-27552064

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